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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/813,012	03/31/2004	Katsumi Horiguchi	251287US3	5269
22850	2850 7590 10/05/2005		EXAMINER	
OBLON, SPIVAK, MCCLELLAND, MAIER & NEUSTADT, P.C. 1940 DUKE STREET ALEXANDRIA, VA 22314			ALANKO, ANITA KAREN	
			ART UNIT	PAPER NUMBER
	•		1765	

DATE MAILED: 10/05/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)		
	10/813,012	HORIGUCHI ET AL.		
Office Action Summary	Examiner	Art Unit		
	Anita K. Alanko	1765		
The MAILING DATE of this communication a Period for Reply	ppears on the cover sheet wit	th the correspondence address		
A SHORTENED STATUTORY PERIOD FOR REF WHICHEVER IS LONGER, FROM THE MAILING - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period. - Failure to reply within the set or extended period for reply will, by state Any reply received by the Office later than three months after the main earned patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUNIC 1.136(a). In no event, however, may a re od will apply and will expire SIX (6) MONT tute, cause the application to become ABA	CATION. sply be timely filed IHS from the mailing date of this communication. ANDONED (35 U.S.C. § 133).		
Status				
 Responsive to communication(s) filed on 3/31/04 filing of application. This action is FINAL. 2b) ☐ This action is non-final. Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213. 				
Disposition of Claims				
4) Claim(s) 1-8 is/are pending in the application 4a) Of the above claim(s) is/are withd 5) Claim(s) is/are allowed. 6) Claim(s) 1-8 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and	rawn from consideration.			
Application Papers				
9) The specification is objected to by the Exami 10) The drawing(s) filed on is/are: a) a Applicant may not request that any objection to the Replacement drawing sheet(s) including the correction. 11) The oath or declaration is objected to by the	ccepted or b) objected to be drawing(s) be held in abeyan ection is required if the drawing(ce. See 37 CFR 1.85(a). s) is objected to. See 37 CFR 1.121(d).		
Priority under 35 U.S.C. § 119				
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 				
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/0 Paper No(s)/Mail Date	Paper No(s	ummary (PTO-413))/Mail Date nformal Patent Application (PTO-152)		

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 1-8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Komura et al (US 5,423,921) in view of Giordani (US 6,833,079) and JP 03-196624A.

Komura discloses a method comprising:

etching a silicon layer (SOI, col.3, lines 26-27) of an object 308 to be processed by employing a patterned mask (col.3, lines 29-30) and by using a plasma of a processing gas introduced into an airtight processing chamber, containing a gaseous mixture of HBr, O_2 and SiF_4 , and additionally SF_6 (col.4, lines 8+, Table 1-Example 1).

Komura fails to disclose to further add a gas containing C and F.

Giordani teaches that it is useful to add a gas containing C and F (CF₄) to an SF₆ plasma gas to obtain a desired effect during etching (col.6, lines 30-32, 41-45).

JP 03-196624A also teaches to add a gas containing C and F to a plasma containing HBr in order to avoid excessive formation of sidewall protective film and achieve anisotropic etching (see abstract).

It would have been obvious to one with ordinary skill in the art to add a gas comprising C and F to the plasma of Komura because Giordani and JP 03-196624A teaches that to do so is useful to achieve a desired profile in the substrate.

As to claim 2, Giordani teaches to add CF₄.

As to claims 3-5, Giordani teaches to add them as desired during only certain steps (col.6, lines 35-40) depending on the desired effect that is desired. It would have been obvious to introduce the gas containing C and F as cited in the modified method of Komura because Giordani teaches that to do so is a known technique for achieving desired effects.

As to claim 6, the modified method of Giordani teaches to add the gas according to the desired effect, and this would encompass according to the diameter since one with ordinary skill in the art knows to vary the diameter of the opening according to the size of the etching opening desired.

As to claim 7, since the modified method of Giordani has the same steps as in the instant invention, it is expected to be capable and obvious to form the cited diameter opening according to the desired final product use.

As to claim 8, Komura discloses to use a silicon oxide mask (col.3, lines 29-30).

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Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. The cited art shows methods of etching silicon.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Anita K. Alanko whose telephone number is 571-272-1458. The examiner can normally be reached on Mon-Fri until 2:30 pm (Wed until 11:30).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nadine Norton can be reached on 571-272-1465. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Anita K Alanko Primary Examiner Art Unit 1765

Anita K. Hanles